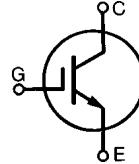


High Voltage, High speed IGBT

IXSH 35N120A

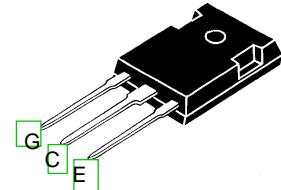
V_{CES} = 1200 V
 I_{C25} = 70 A
 $V_{CE(sat)}$ = 4 V

Short Circuit SOA Capability



Symbol	Test Conditions	Maximum Ratings		
V_{CES}	$T_J = 25^\circ\text{C}$ to 150°C	1200		V
V_{CGR}	$T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1 \text{ M}\Omega$	1200		V
V_{GES}	Continuous	± 20		V
V_{GEM}	Transient	± 30		V
I_{C25}	$T_c = 25^\circ\text{C}$	70		A
I_{C90}	$T_c = 90^\circ\text{C}$	35		A
I_{CM}	$T_c = 25^\circ\text{C}$, 1 ms	140		A
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}$, $T_J = 125^\circ\text{C}$, $R_G = 22 \Omega$ Clamped inductive load, $L = 30 \mu\text{H}$	$I_{CM} = 70$ @ 0.8 V_{CES}		A
t_{sc} (SCSOA)	$V_{GE} = 15 \text{ V}$, $V_{CE} = 0.6 \cdot V_{CES}$, $T_J = 125^\circ\text{C}$ $R_G = 22 \Omega$, non repetitive	10		μs
P_c	$T_c = 25^\circ\text{C}$	300		W
T_J		-55 ... +150		$^\circ\text{C}$
T_{JM}		150		$^\circ\text{C}$
T_{stg}		-55 ... +150		$^\circ\text{C}$
M_d	Mounting torque	1.13/10	Nm/lb.in.	
Weight		6		g
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300		$^\circ\text{C}$

TO-247 AD



G = Gate, C = Collector,
E = Emitter, TAB = Collector

Symbol	Test Conditions	Characteristic Values		
		($T_J = 25^\circ\text{C}$, unless otherwise specified)		
BV_{CES}	$I_c = 3 \text{ mA}$, $V_{GE} = 0 \text{ V}$	1200		V
$V_{GE(th)}$	$I_c = 4 \text{ mA}$, $V_{CE} = V_{GE}$	4	6	V
I_{CES}	$V_{CE} = 0.8 \cdot V_{CES}$ $V_{GE} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		$400 \mu\text{A}$ 1.2 mA
I_{GES}	$V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$I_c = I_{C90}$, $V_{GE} = 15 \text{ V}$			4 V

Features

- International standard package JEDEC TO-247
- High frequency IGBT with guaranteed Short Circuit SOA capability
- Fast Fall Time for switching speeds up to 20 kHz
- 2nd generation HDMOS™ process
- Low $V_{CE(sat)}$
 - for minimum on-state conduction losses
- MOS Gate turn-on
 - drive simplicity

Applications

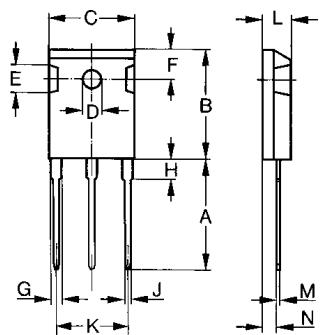
- AC motor speed control
- DC servo and robot drive
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies
- Welding

Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- High power density

Symbol	Test Conditions	Characteristic Values			
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.	max.
g_{fs}	$I_C = I_{C90}$; $V_{CE} = 10 \text{ V}$, Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$	20	26	S	
$I_{C(on)}$	$V_{GE} = 15 \text{ V}$, $V_{CE} = 10 \text{ V}$		170	A	
C_{ies}	$V_{CE} = 25 \text{ V}$, $V_{GE} = 0 \text{ V}$, $f = 1 \text{ MHz}$	3750		pF	
C_{oes}		235		pF	
C_{res}		60		pF	
Q_g	$I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $V_{CE} = 0.5 V_{CES}$	150	190	nC	
Q_{ge}		40	60	nC	
Q_{gc}		70	100	nC	
$t_{d(on)}$	Inductive load, $T_J = 25^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $L = 100 \mu\text{H}$ $V_{CE} = 0.8 V_{CES}$, $R_G = 2.7 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) > $0.8 \cdot V_{CES}$, higher T_J or increased R_G	80		ns	
t_{ri}		150		ns	
$t_{d(off)}$		400	900	ns	
t_{fi}		500	700	ns	
E_{off}		10		mJ	
$t_{d(on)}$	Inductive load, $T_J = 125^\circ\text{C}$ $I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$, $L = 100 \mu\text{H}$ $V_{CE} = 0.8 V_{CES}$, $R_G = 2.7 \Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) > $0.8 \cdot V_{CES}$, higher T_J or increased R_G	80		ns	
t_{ri}		150		ns	
E_{on}		2.5		mJ	
$t_{d(off)}$		400		ns	
t_{fi}		700		ns	
E_{off}		15		mJ	
R_{thJC}			0.42	K/W	
R_{thCK}		0.25		K/W	

TO-247 AD (IXSH) Outline



Dim.	Millimeter Min.	Max.	Inches Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

Fig.1 Saturation Characteristics

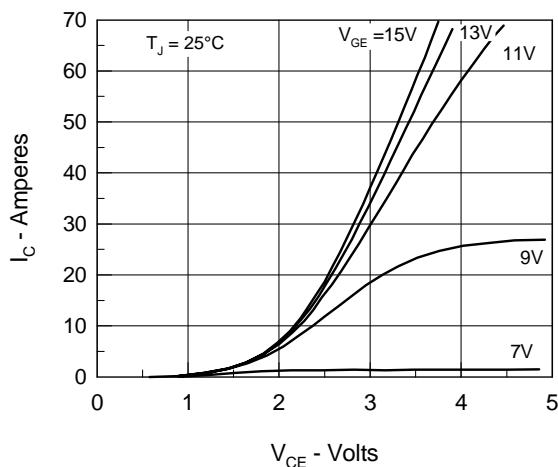


Fig.3 Collector-Emitter Voltage vs. Gate-Emitter Voltage

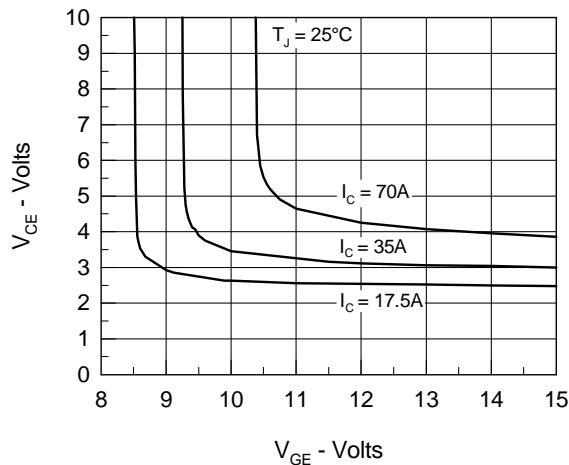


Fig.5 Input Admittance

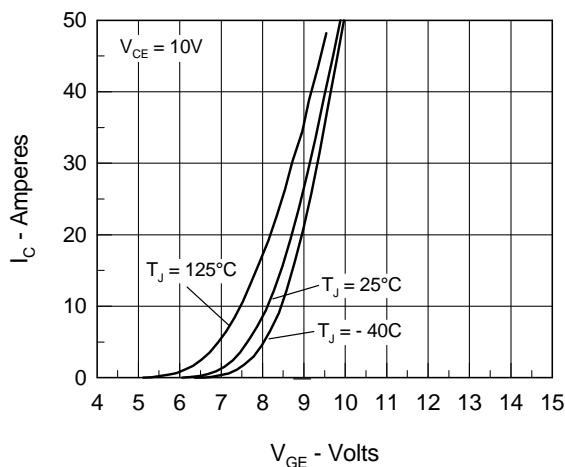


Fig.2 Output Characteristics

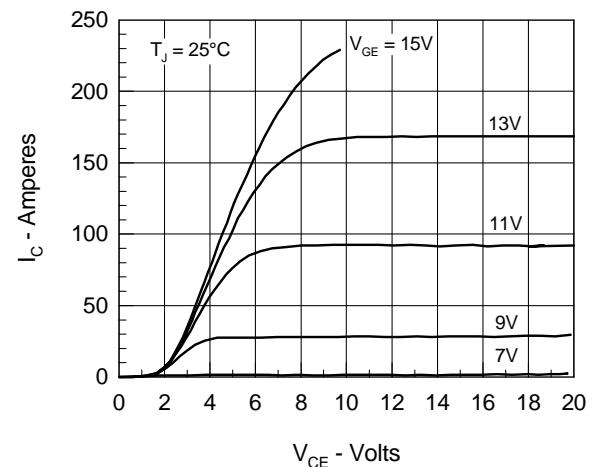


Fig.4 Temperature Dependence of Output Saturation Voltage

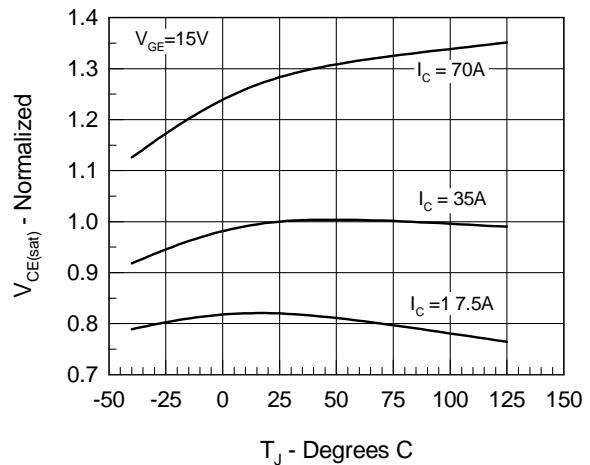


Fig.6 Temperature Dependence of Breakdown and Threshold Voltage

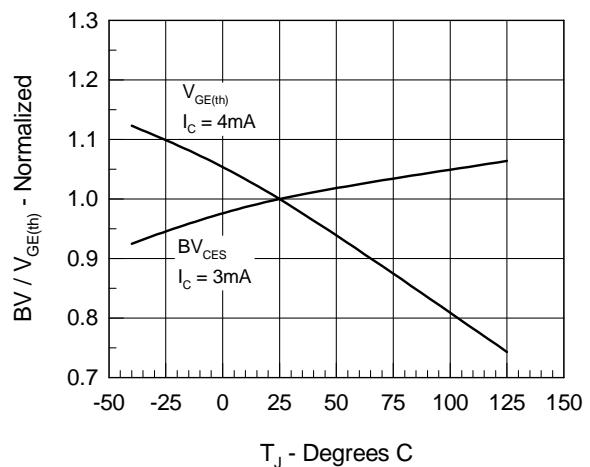


Fig.7 Turn-Off Energy per Pulse and Fall Time on Collector Current

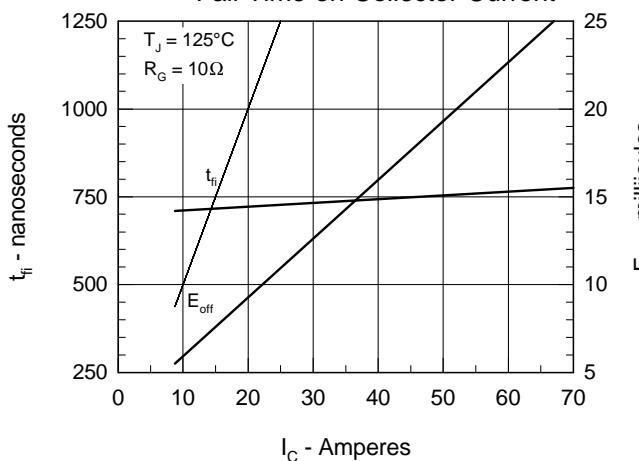


Fig.8 Dependence of Turn-Off Energy Per Pulse and Fall Time on R_G

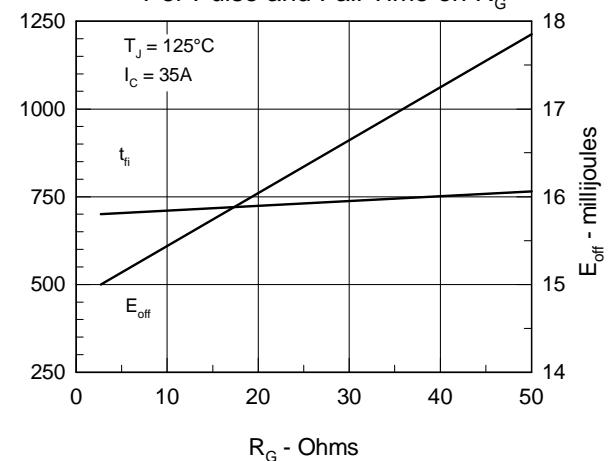


Fig.9 Gate Charge Characteristic Curve

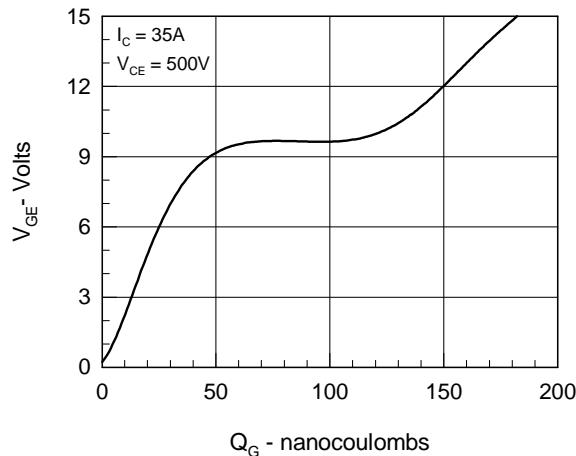


Fig.10 Turn-Off Safe Operating Area

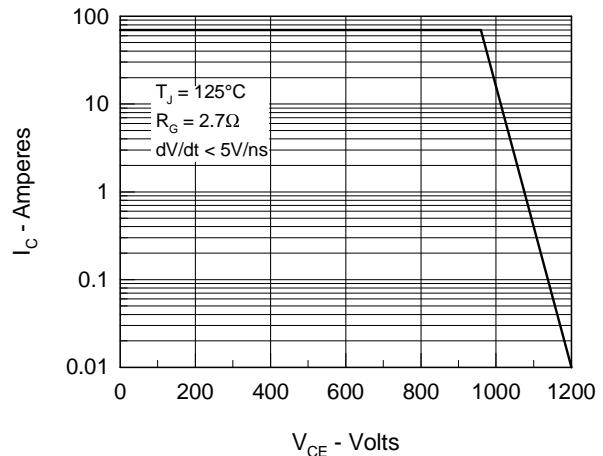


Fig.11 Transient Thermal Impedance

